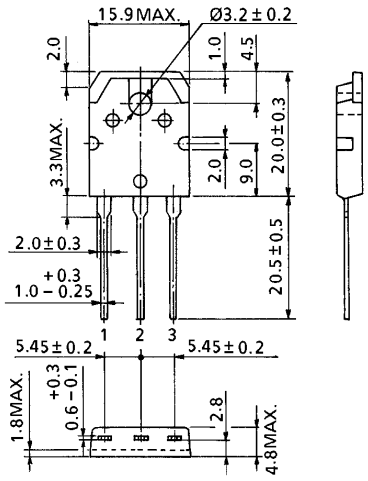
TOSHIBA TRANSISTOR SILICON PNP TRIPLE DIFFUSED TYPE

2SA1941

POWER AMPLIFIER APPLICATIONS

- Complementary to 2SC5198
- Recommend for 70W High Fidelity Audio Frequency Amplifier Output Stage

Unit in mm



1. BASE
2. COLLECTOR (HEAT SINK)
3. EMITTER

JEDEC	—
JEITA	—
TOSHIBA	2-16C1A

Weight : 4.7g (Typ.)

MAXIMUM RATINGS (Tc = 25°C)

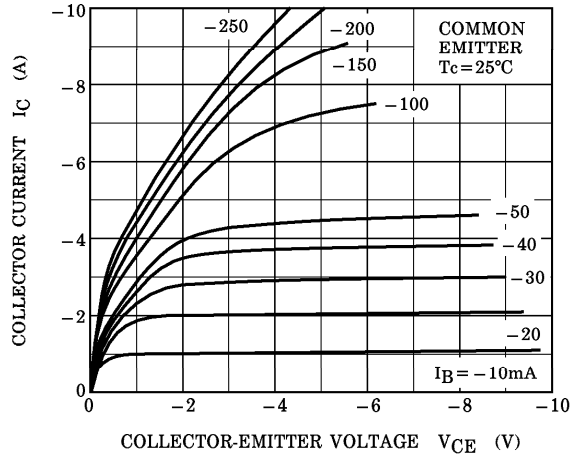
CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	−140	V
Collector-Emitter Voltage	V_{CEO}	−140	V
Emitter-Base Voltage	V_{EBO}	−5	V
Collector Current	I_C	−10	A
Base Current	I_B	−1	A
Collector Power Dissipation (Tc = 25°C)	P_C	100	W
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	−55~150	°C

ELECTRICAL CHARACTERISTICS (Tc = 25°C)

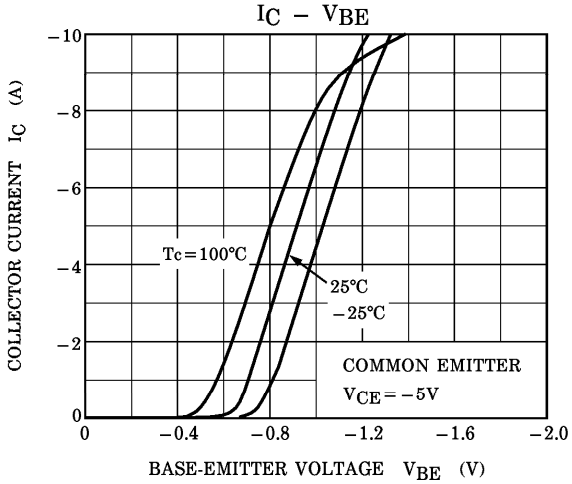
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	V_{CB} = −140V, I_E = 0	—	—	−5.0	μA
Emitter Cut-off Current	I_{EBO}	V_{EB} = −5V, I_C = 0	—	—	−5.0	μA
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	I_C = −50mA, I_B = 0	−140	—	—	V
DC Current Gain	$h_{FE(1)}$ (Note)	V_{CE} = −5V, I_C = −1A	55	—	160	
	$h_{FE(2)}$	V_{CE} = −5V, I_C = −5A	35	83	—	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	I_C = −7A, I_B = −0.7A	—	−0.8	−2.0	V
Base-Emitter Voltage	V_{BE}	V_{CE} = −5V, I_C = −5A	—	−1.0	−1.5	V
Transition Frequency	f_T	V_{CE} = −5V, I_C = −1A	—	30	—	MHz
Collector Output Capacitance	C_{ob}	V_{CB} = −10V, I_E = 0, f = 1MHz	—	320	—	pF

(Note) : $h_{FE(1)}$ Classification R : 55~110, O : 80~160

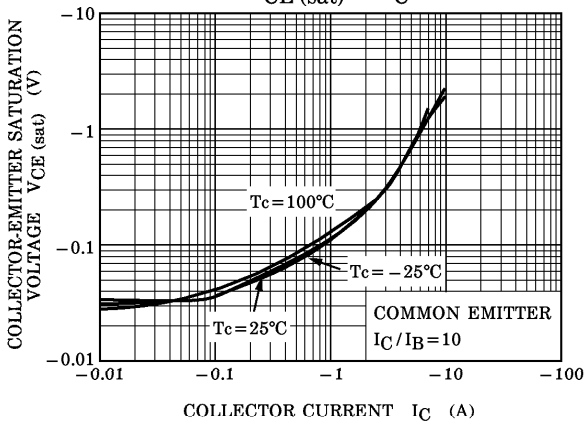
I_C – V_{CE}



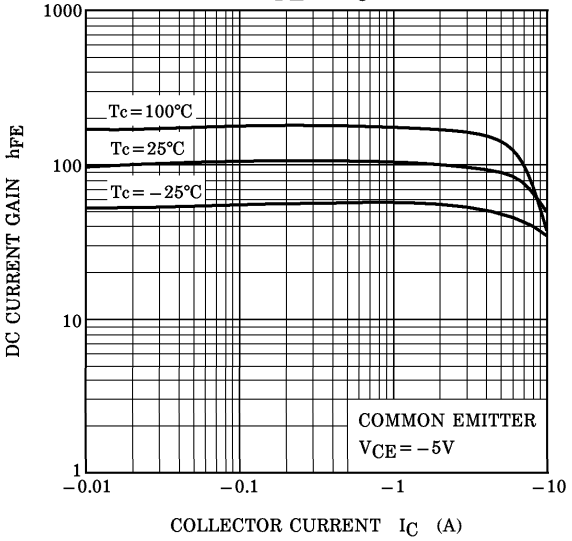
I_C – V_{BE}



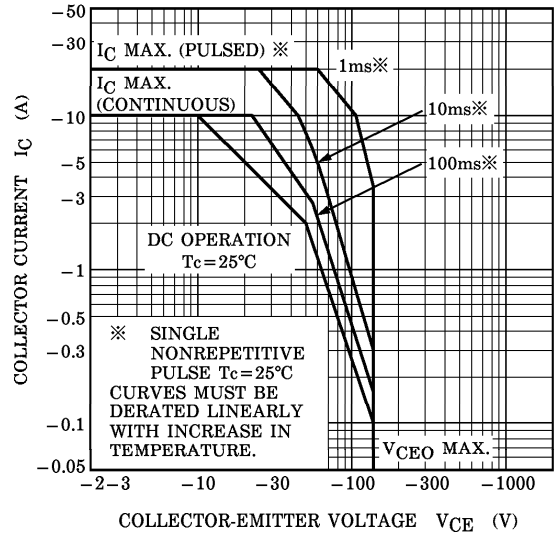
$V_{CE\,(sat)}$ – I_C



h_{FE} – I_C



SAFE OPERATING AREA



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